Materials	SAUERSCHNIG Philipp 博士(工学) 博甲第9389号 令和2年3月25日 学位規則第4条第1項該 数理物質科学研究科 orides and Heusler Alloys as High and としての多ホウ化物及び Heusler 合金	Low Temperature	Thermoelectric
主查	筑波大学教授(連係大学院)	博士(理学)	森孝雄
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論文の要旨

The main focus of this work is the investigation and development of new materials forthe high and room temperature ranges. REB₆₆ compounds and boron carbide were selected to investigate as well as the Full Heusler alloy Fe₂VAl for the high and low temperature regimes, respectively. Magnetic effects in thermoelectrics are also of interest and investigated. SmB₆₆ was previously indicated to have enhanced properties possibly because of mixed valency effect of Sm. Single crystalline YbB₆₆ as well as polycrystalline REB₆₆ (RE=Y, Sm, Ho, Tm, Yb) fabricated for the first time by a synthesis route involving arc melting and spark plasma sintering were investigated in the applicant's work. Strikingly, the thermoelectric properties of these compounds were discovered to be almost independent of the microstructure. The nature of the rare earth also found not to strongly affect the thermoelectric properties, differences originating mainly from different compositions or the presence of secondary phases. Relatively large negative Curie-Weiss temperatures θ were observed with unusual rare earth dependence indicative of an unusualcoupling mechanism. The thermoelectric properties of phase-pure carbon-rich boron carbide B_{4.05}C synthesized from a sucrose precursor by a solution-based method were reported and discussed using commercially available boron carbide powders as references. Electrical conduction mechanisms of boron carbide are also discussed, and the nearest-neighbor hopping conduction model was concluded to bemore valid than the often-used bipolaron model. The work on the Full Heusler alloy Fe₂VAl dealt with the connection of thermoelectric and magnetic properties via spin fluctuation. V was successfully substituted with Co resulting in ferromagnetic materials with Curie-temperatures shifted towards higher temperatures and maximum in the Seebeck enhancement could be observed at or above room temperature.

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The applicant synthesized and investigated the properties of high temperature and room temperature thermoelectric materials which are maybe the most viable regions for future applications. In particular the thermoelectric and magnetic properties of REB₆₆ were analyzed carefully. A previous study indicated that SmB₆₆ has enhanced properties indicated from mixed valency, however, the applicant obtained similar good properties in other REB₆₆ which were indicated from magnetic properties to be trivalent, and the good properties origin were able to be attributed to metal rich compositions, with not much rare earth dependence apparent. Polycrystalline REB₆₆ (RE=Y, Sm, Ho, Tm, Yb) were fabricated for the first time by a synthesis route involving arc melting and spark plasma sintering, which is much easier than the typical single crystal growth method, and strikingly, with thermoelectric properties similar to single crystals, indicating an independence of the microstructure. A different conduction mechanism from the usually assumed bipolaron conduction mechanism, was proposed for the prototypical boride thermoelectric material, boron carbide. Magnetic and thermoelectric properties of Co doped Fe₂VAl were found to be able to be controlled, with the transition temperature shifted to higher temperatures and the enhancement from spin fluctuation reaching a maximum at room temperature. The applicant has achieved interesting results into synthesis and investigation of thermoelectrical and magnetic properties. These achievements should accelerate the research, especially on higher boride thermoelectrics going forward. It is judged that the work by the applicant merits awarding of PhD of Engineering.

[最終試験結果]

The final examination committee conducted a meeting as a final examination on February17, 2020. The applicant provided an overview of dissertation, addressed questions and comments raised during Q&A session. All of the committee members reached a final decision that the applicant has passed the final examination.

[結論]

Based on the results of the above-mentioned dissertation defense and final examination, the final examination committee approved that the applicant is qualified to be awarded Doctor of Philosophy in Engineering.